

	Type	Hits	Search Text	DBs
1	BRS	19309	trench with isolation	US-PGPUB; USPAT
2	BRS	2736	S1 and well and source and drain and (polysilicon adj gate).	US-PGPUB; USPAT
3	BRS	1736	S2 and (oxide with trench)	US-PGPUB; USPAT
4	BRS	683	S3 and (trench with dielectric)	US-PGPUB; USPAT
5	IS&R	1	("20040224476").PN.	US-PGPUB; USPAT
6	BRS	1084	sacrificial adj oxide same trench	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
7	BRS	570	S6 and well and source and drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
8	BRS	232	S7 and ((dry adj etch) or (dry adj etching))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
9	BRS	29	simultaneous with trench with gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
10	BRS	2133	438/296,424,430.ccls.	US-PGPUB; USPAT
11	BRS	664	S10 and (trench with isolation) and well and source and drain	US-PGPUB; USPAT